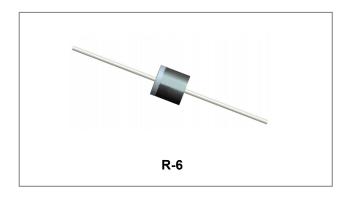


ST1550AX

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ST1550AX SCHOTTKY BARRIER RECTIFIER



Features

- 150°C T_J operation
- Center tap configuration
- Ultralow forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Circuit Diagram



Applications

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	-	50	V
Average Rectified Forward Current	I _{F (AV)}	50% duty cycle $@T_c$ = 75°C, rectangular wave form	15	А
Peak One Cycle Non-Repetitive Surge Current	IFSM	8.3 ms, half Sine pulse, T_C= 25°C	200	A

Electrical Characteristics:

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop*		@ 5A, Pulse, TJ = 25 °C	0.38	-	
	V _{F1}	@ 7.5A, Pulse, TJ = 25 °C	0.41	-	V
		@ 15A, Pulse, T」 = 25 °C	0.48	0.56	
		@ 5A, Pulse, T _J = 125 °C	0.26	-	
	V _{F2}	@ 7.5A, Pulse, TJ = 125 °C	0.31	-	V
		@ 15A, Pulse, T」 = 125 °C	0.41	0.50	
Reverse Current*	I _{R1}	$@V_R = rated V_{R, T_J} = 25 \ ^{\circ}C$	0.14	3	mA
	I _{R2}	@V _R = rated V _R , T _J = 125 °C	60	140	mA
Junction Capacitance	Ст	@V _R = 5V, T _C = 25 °C f _{SIG} = 1MHz	1100	-	pF

* Pulse width < 300 μ s, duty cycle < 2%

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- http://www.smc-diodes.com sales@ smc-diodes.com •



ST1550AX

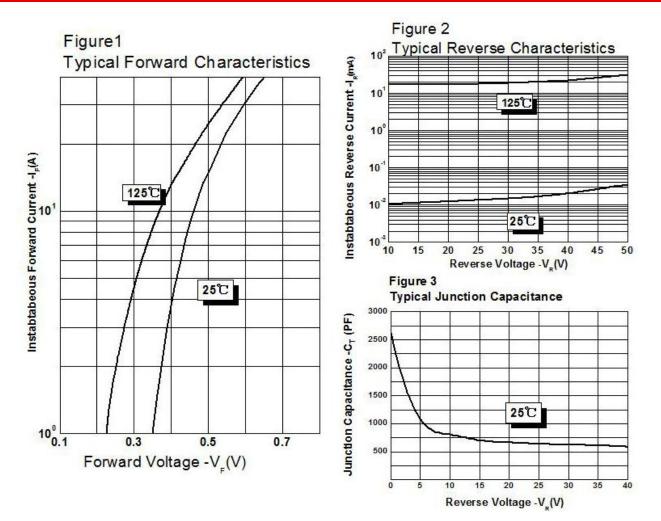
RoHS 🗭

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Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +150	°C
Storage Temperature	T _{stg}	-	-55 to +150	°C
Typical Thermal Resistance Junction to Ambient	$R_{ heta JA}$	DC operation	45	°C/W
Approximate Weight	wt	-	2.24	g
Case Style		R-6		•

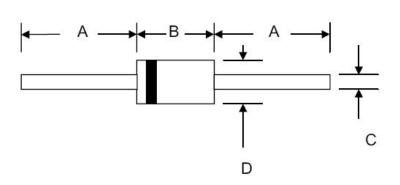
Ratings and Characteristics Curves





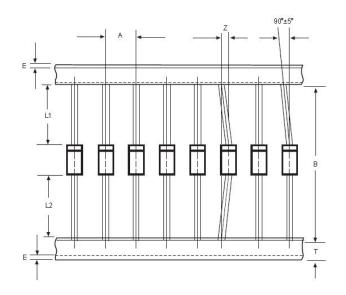
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Mechanical Dimensions R-6



SYMBOL	Millin	neters	Inc	Inches		
STMBOL	Min.	Max.	Min.	Max.		
A	25.4	-	1.000	-		
В	8.60	9.10	0.340	0.360		
С	1.2	1.3	0.048	0.052		
D	8.60	9.10	0.340	0.360		

Carrier Tape Specification R-6



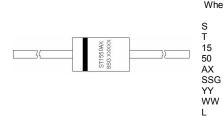
SYMBOL	Millimeters		
	Min.	Max.	
А	9.50	10.50	
В	50.9	53.9	
Z	-	1.20	
Т	5.60	6.40	
E	-	0.80	
IL1-L2I	_	1.0	

Ordering Information

Device	Package	Shipping
ST1550AX	R-6(Pb-Free)	500pcs / reel

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

Marking Diagram



Where XXXXX is YYWWL

- = Device Type = Ultralow VF
- = Ontailow VP = Forward Current (15A) = Reverse Voltage (50V) = Package type = SSG

- = Year
- = Week = Lot Number

Cautions: Molding resin Epoxy resin UL:94V-0

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